



DESCRIPTION:

The CENTRAL SEMICONDUCTOR CSHD3-60, silicon schottky rectifier is a high quality, well constructed, highly reliable component designed for use in all types of commercial, industrial, entertainment, computer and automotive applications.

MARKING CODE: FULL PART NUMBER

MAXIMUM RATINGS: (T_C=25°C unless otherwise noted)

	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V _{RRM}	60	V
Average Rectified Forward Current (T _C =120°C)	IO	3.0	А
Peak Forward Surge Current (tp=10ms)	IFSM	50	А
Peak Repetitive Reverse Surge Current (tp=2µs)	IRRM	1.0	А
Critical Rate of Rise of Reverse Voltage	dv/dt	10,000	V/µs
Operating and Storage			
Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	ΘJC	3.5	°C/W

ELECTRICAL CHARACTERISTICS: (T_C=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
I _R	V _R =60V		30	μΑ
I _R	V _R =60V, T _C =125°C		10	mA
V _F	I _F =3.0A		0.75	V
۷ _F	I _F =3.0A, T _C =125°C		0.70	V

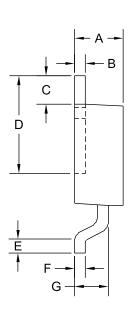
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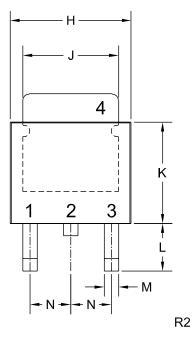


CSHD3-60

SURFACE MOUNT SCHOTTKY SILICON RECTIFIER SINGLE, 3.0 AMPS, 60 VOLTS

DPAK RECTIFIER CASE - MECHANICAL OUTLINE



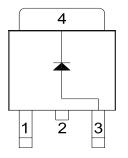


LEAD CODE:

NO CONNECTION
CATHODE
ANODE
CATHODE

PIN 2 IS COMMON TO THE TAB (4).

MARKING CODE: FULL PART NUMBER



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
Α	0.083	0.108	2.10	2.75		
В	0.016	0.024	0.40	0.60		
С	0.063		1.60			
D	0.203	0.219	5.15	5.55		
E	0.039		1.00			
F	0.020		0.50			
G	0.051	0.071	1.30	1.80		
Н	0.248	0.268	6.30	6.80		
J	0.197	0.217	5.00	5.50		
K	0.209	0.224	5.30	5.70		
L	0.090	0.106	2.30	2.70		
М	0.012	0.031	0.30	0.80		
N	0.091		2.30			
DPAK RECTIEIER (REV: R2)						

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